LME49723 Dual High Fidelity Audio Operational Amplifier



Literature Number: SNAS429A

0.0002% (typ)

0.3mV (typ)

LME49723 **Dual High Fidelity Audio Operational Amplifier**

General Description

The LME49723 is part of the ultra-low distortion, low noise, high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49723 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49723 combines extremely low voltage noise density $(3.6 \text{nV}/\sqrt{\text{Hz}})$ with vanishingly low THD+N (0.0002%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49723 has a high slew rate of ±20V/µs and an output current capability of ±26mA. Further, dynamic range is maximized by an output stage that drives $2k\Omega$ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads.

The LME49723's outstanding CMRR (100dB), PSRR (100dB), and V_{OS} (0.3mV) give the amplifier excellent operational amplifier DC performance.

The LME49723 has a wide supply range of ±2.5V to ±17V. Over this supply range the LME49723's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49723 is unity gain stable.

The LME49723 is available in an 8-lead narrow body SOIC. Demonstration boards are available for each package.

Key Specifica

Power Supply Volta

THD+N ($A_V = 1$, $V_{OUT} = 3V_{BMS}$, $f_{IN} = 1$ kHz)

150Ω

 $R_1 = 2k\Omega$

Typical Application

10 pF

INPUT

R_L	=	600Ω	

- Input Noise Density $3.6 \text{nV} / \sqrt{\text{Hz}}$ (typ)
- Slew Rate ±8V/µs (typ) Gain Bandwidth Product 17MHz (typ) 105dB (typ)
- Open Loop Gain (R₁ = 600Ω)
- Input Bias Current 200nA (typ)
- Input Offset Voltage

Features

- Easily drives 600Ω loads
- Optimized for superior audio signal fidelity
- Output short circuit protection
- PSRR and CMRR exceed 100dB (typ)
- SOIC package

Applications

- High quality audio amplification
- High fidelity preamplifiers
- High fidelity multimedia
- Phono pre amps
- High performance professional audio
- High fidelity equalization and crossover networks

3320Ω

₩₩

LME49723

- High performance line drivers
- High performance line receivers
- High fidelity active filters

150Ω

 $3.83 \ \text{k}\Omega$

47 nF//33 nF

100Ω



Note: 1% metal film resistors, 5% polypropylene capacitors

3320Ω

₩₩

300362k5

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OUTPUT



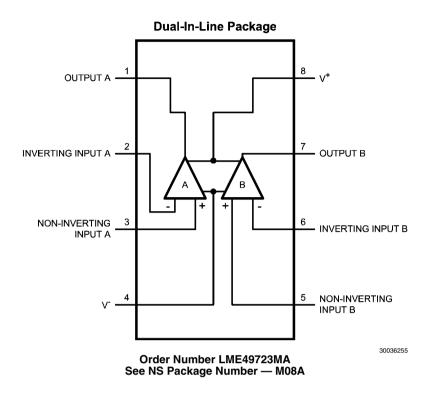
tions	
age Range	±2.5V to ±17V

0.0002% (typ)

26.1 kΩ

Passively Equalized RIAA Phono Preamplifier

Connection Diagram



Absolute Maximum Ratings (Notes 1, 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/

Distributors for availability a	ind specifications.	Junction Temperature	150°C
Power Supply Voltage		Thermal Resistance	
$(V_s = V^+ - V^-)$	36V	θ _{JA} (SO)	145°C/W
Storage Temperature	–65°C to 150°C	Temperature Range	
Input Voltage	(V-) - 0.7V to (V+) + 0.7V	$T_{MIN} \le T_A \le T_{MAX}$	$-40^{\circ}C \le T_{A} \le 85^{\circ}C$
Output Short Circuit (Note 3)	Continuous	Supply Voltage Range	$\pm 2.5V \le V_S \le \pm 17V$

Power Dissipation

ESD Susceptibility (Note 4)

ESD Susceptibility (Note 5)

Electrical Characteristics for the LME49723 (Notes 1, 2) The specifications apply for $V_s = \pm 15V$, $R_L = 2k\Omega$, $f_{IN} = 1$ kHz, $T_A = 25^{\circ}$ C, unless otherwise specified.

			LME	LME49723		
Symbol	Parameter	Conditions	Typical Limit		Units	
			(Note 6)	(Note 7)	(Limits)	
		$A_V = 1, V_{OUT} = 3V_{rms}$				
THD+N	Total Harmonic Distortion + Noise	$R_L = 2k\Omega$	0.0002		% (max)	
		$R_L = 600\Omega$	0.0002	0.0004		
IMD	Intermodulation Distortion	A _V = 1, V _{OUT} = 3V _{RMS} Two-tone, 60Hz & 7kHz 4:1	0.0005		%	
GBWP	Gain Bandwidth Product		19	15	MHz (min)	
SR	Slew Rate		±8	±6	V/µs (min)	
FPBW	Full Power Bandwidth	$V_{OUT} = 1V_{P-P}$, -3dB referenced to output magnitude at f = 1kHz	4		MHz	
٥	Equivalent Input Noise Voltage	f _{BW} = 20Hz to 20kHz	0.45	0.65	μV _{RMS} (max)	
e _n	Equivalent Input Noise Density	f = 1kHz f = 10Hz	3.2 8.5	5	nV/√Hz (max)	
i _n	Current Noise Density	f = 1kHz f = 10Hz	0.7 1.3		pA / √Hz	
V _{OS}	Offset Voltage		±0.3	1	mV (max)	
ΔV _{OS} /ΔTemp	Average Input Offset Voltage Drift vs Temperature	–40°C ≤ T _A ≤ 85°C	0.2		μV/°C	
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	ΔV _S = 20V (Note 8)	100	95	dB (min)	
ISO _{CH-CH}	Channel-to-Channel Isolation	f _{IN} = 1kHz f _{IN} = 20kHz	118 112		dB	
I _B	Input Bias Current	$V_{CM} = 0V$	200	300	nA (max)	
ΔI _{OS} /ΔTemp	Input Bias Current Drift vs Temperature	–40°C ≤ T _A ≤ 85°C	0.1		nA/°C	
I _{OS}	Input Offset Current	$V_{CM} = 0V$	7	100	nA (max)	
V _{IN-CM}	Common-Mode Input Voltage Range		±14	(V+) - 2.0 (V-) + 2.0	V (min)	
CMRR	Common-Mode Rejection	-10V <vcm<10v< td=""><td>100</td><td>90</td><td>dB (min)</td></vcm<10v<>	100	90	dB (min)	
7	Differential Input Impedance		30		kΩ	
Z _{IN}	Common Mode Input Impedance	-10V <vcm<10v< td=""><td>1000</td><td></td><td>MΩ</td></vcm<10v<>	1000		MΩ	
		–10V <vout<10v, r<sub="">L = 600Ω</vout<10v,>	100	98	dB (min)	
A _{VOL}	Open Loop Voltage Gain	-10V <vout<10v, <math="">R_L = 2k\Omega</vout<10v,>	105			
		$-10V < Vout < 10V, R_{L} = 10k\Omega$	105	1		

Internally Limited

800V

180V

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2

	Parameter	Conditions	LME4	LME49723	
Symbol			Typical	Limit	– Units – (Limits)
			(Note 6)	(Note 7)	
		R _L = 600Ω	±13.5	±12.5	
V _{OUTMAX}	Maximum Output Voltage Swing	$R_L = 2k\Omega$	±14.0		V (min)
		$R_L = 10k\Omega$	±14.1		
I _{OUT}	Output Current	R _L = 600Ω, V _S = ±17V	±25	±21	mA (min)
1	Instantaneous Short Circuit Current		+53		mA
OUT-CC	Instantaneous Short Circuit Current		-42		
		f _{IN} = 10kHz			
R _{OUT}	Output Impedance	Closed-Loop	0.01		Ω
		Open-Loop	13		
C _{LOAD}	Capacitive Load Drive Overshoot	100pF	16		%
I _S	Total Quiescent Current	I _{OUT} = 0mA	6.7	7.5	mA (max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

Note 2: Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 3: Amplifier output connected to GND, any number of amplifiers within a package.

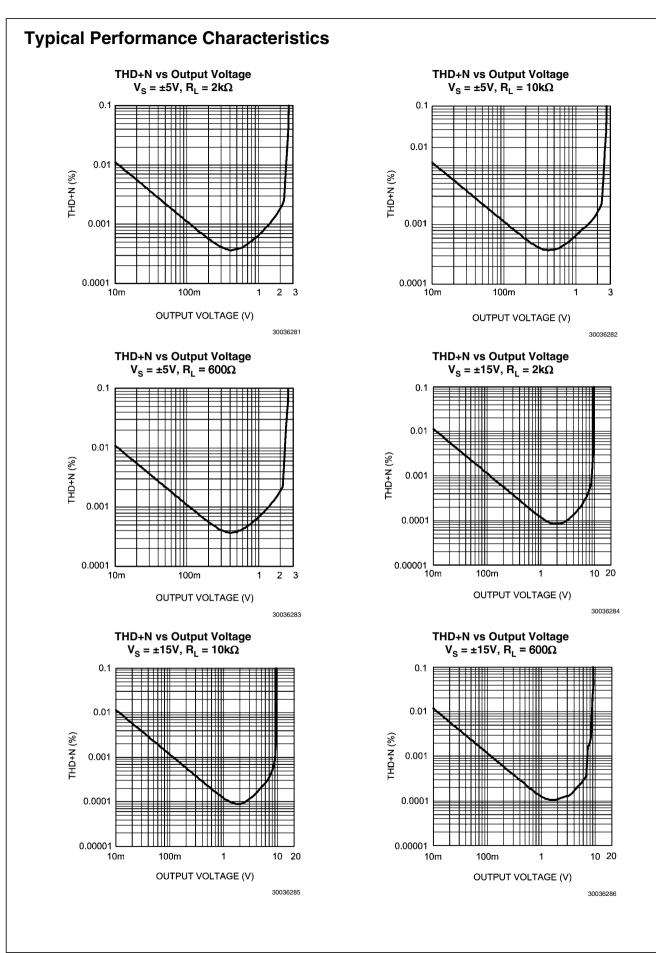
Note 4: Human body model, 100pF discharged through a 1.5k Ω resistor.

Note 5: Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50Ω).

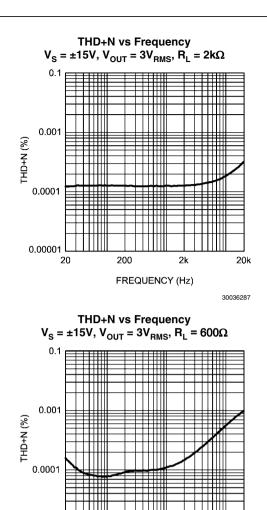
Note 6: Typical specifications are specified at +25°C and represent the most likely parametric norm.

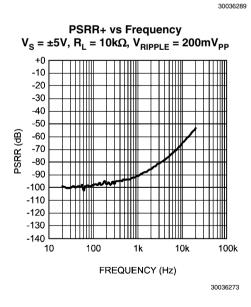
Note 7: Tested limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

Note 8: PSRR is measured as follows: V_{OS} is measured at two supply voltages, ±5V and ±15V. PSRR = | $20log(\Delta V_{OS}/\Delta V_S)$ |.









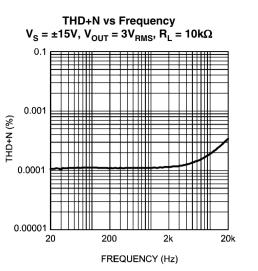
200

2k

FREQUENCY (Hz)

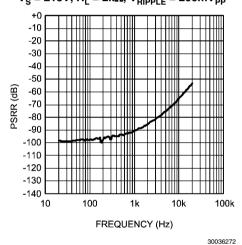
20k

0.00001



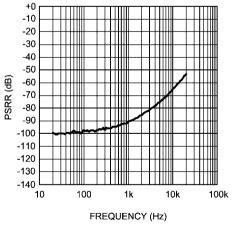
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PSRR+ vs Frequency $V_s = \pm 15V, R_L = 2k\Omega, V_{RIPPLE} = 200mV_{PP}$

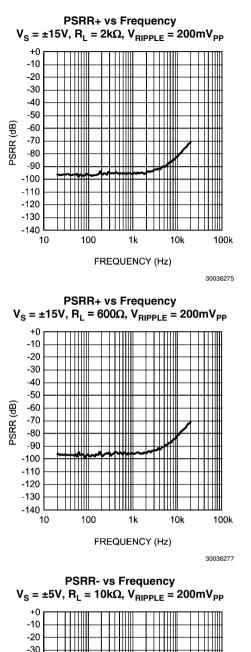


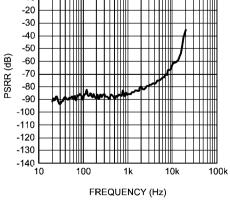
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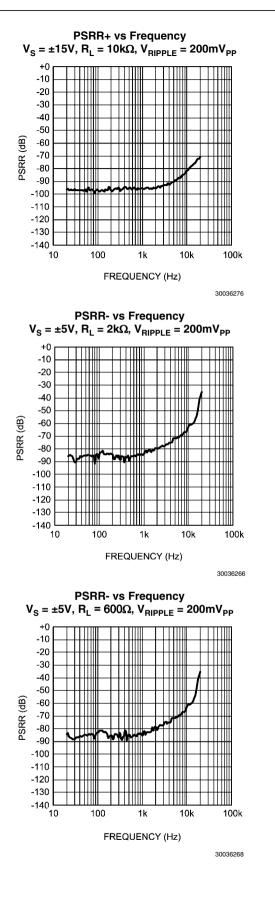
PSRR+ vs Frequency $V_s = \pm 5V, R_L = 600\Omega, V_{RIPPLE} = 200mV_{PP}$

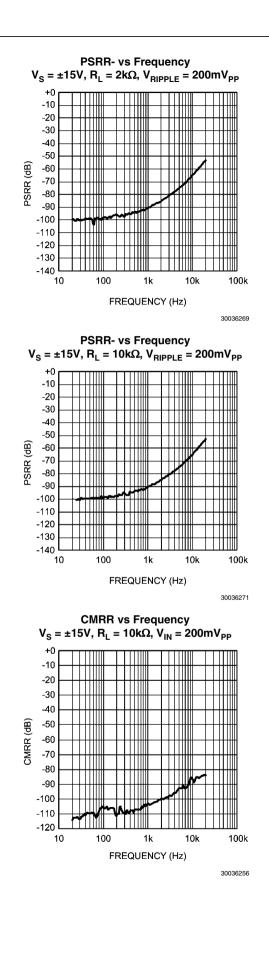


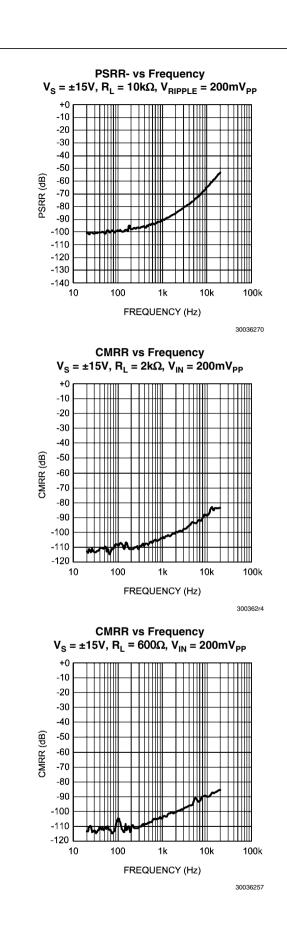
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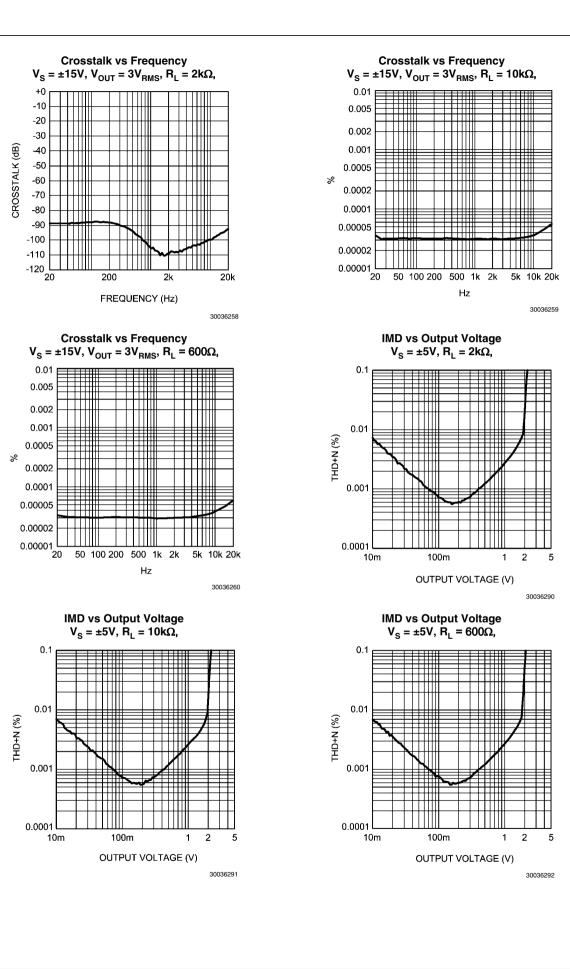




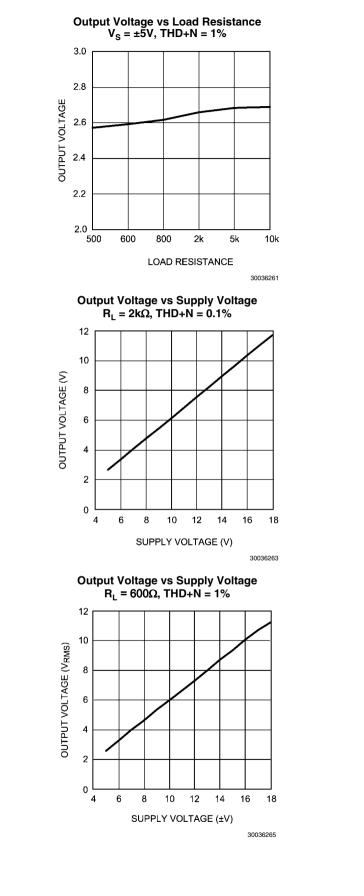


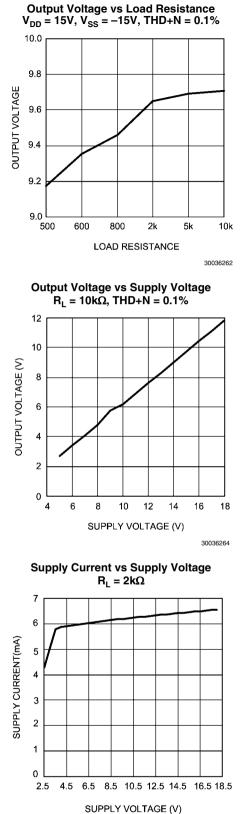




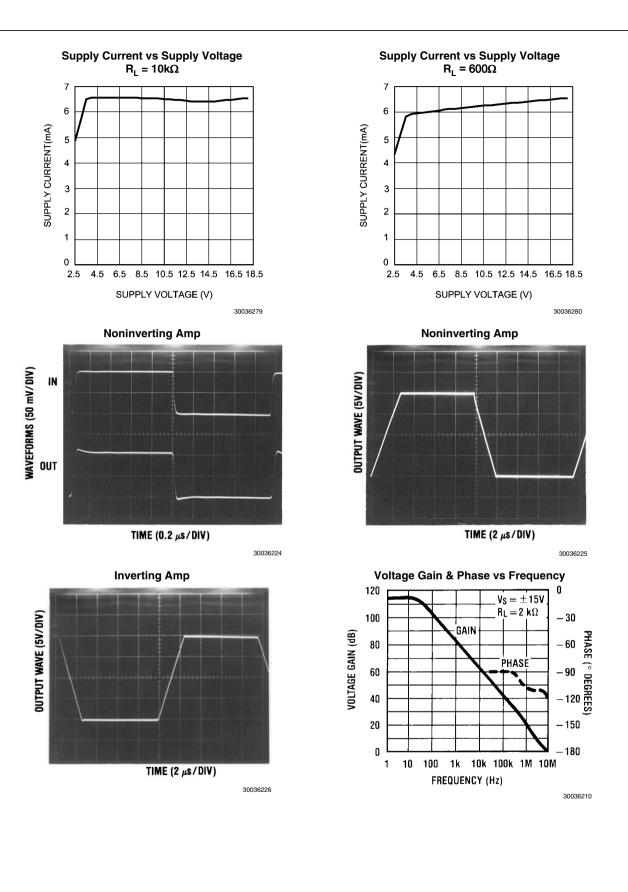




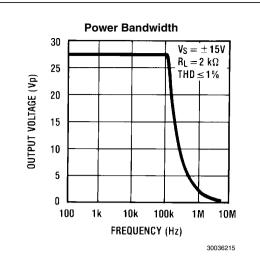




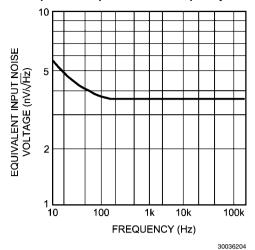








Equivalent Input Noise vs Frequency



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Application Information

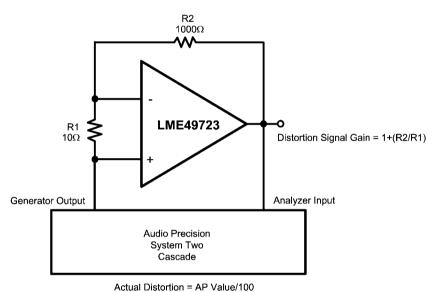
DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LME49723 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LME49723's low residual distortion is an input referred internal error. As shown in Figure 1, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting

inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 1.

This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.



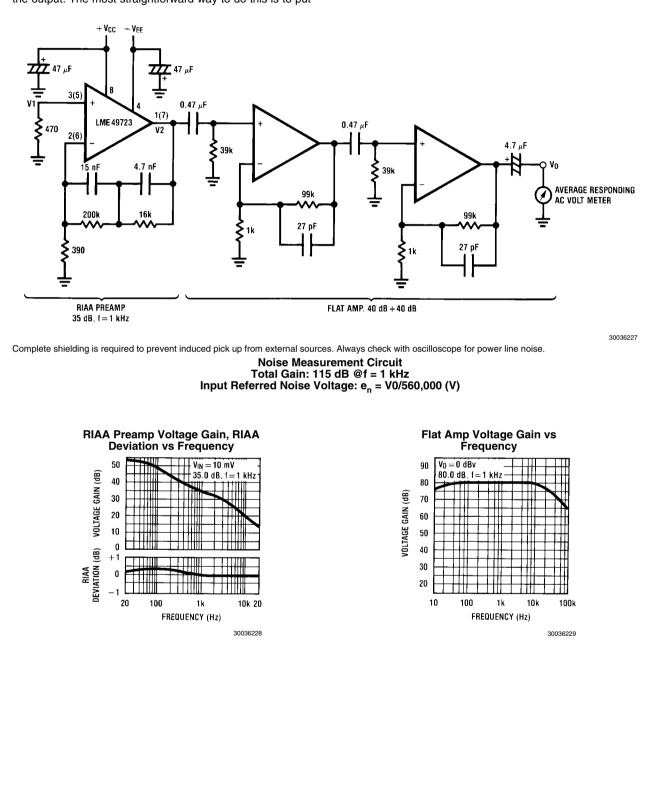
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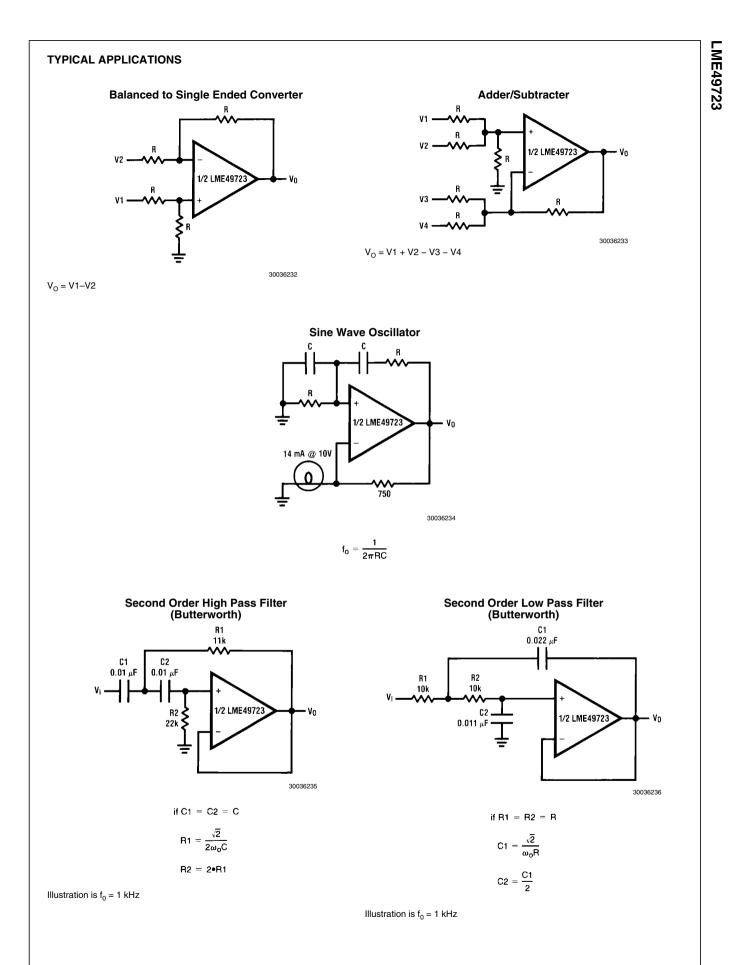
FIGURE 1. THD+N and IMD Distortion Test Circuit

The LME49723 is a high speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

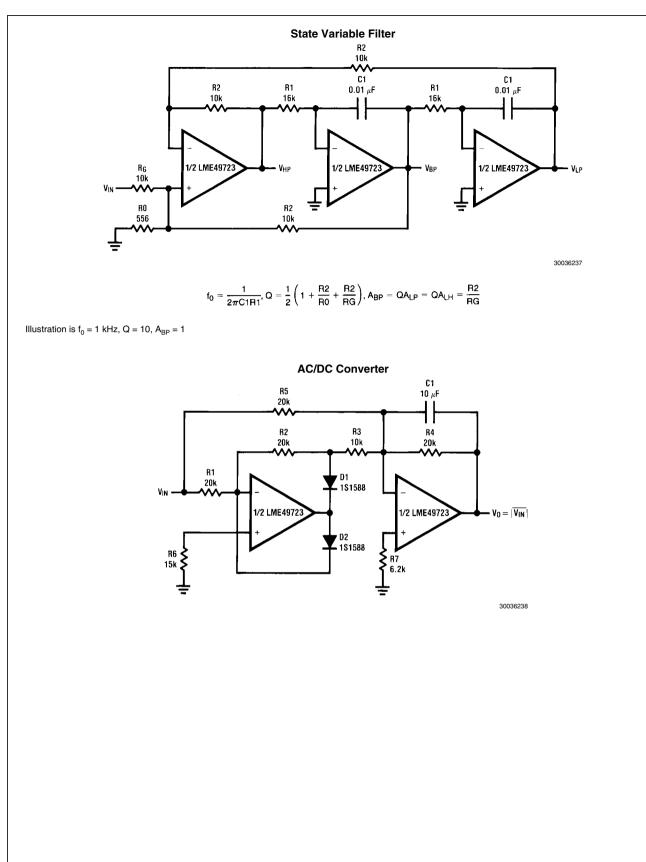
a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

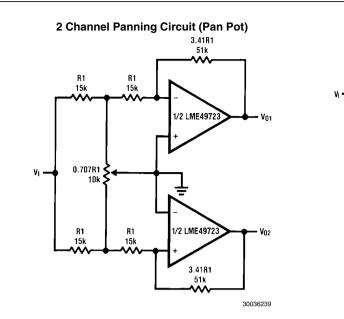
Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put

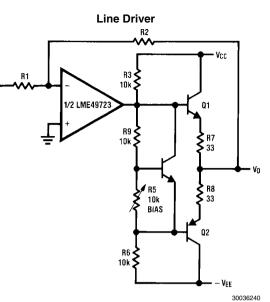


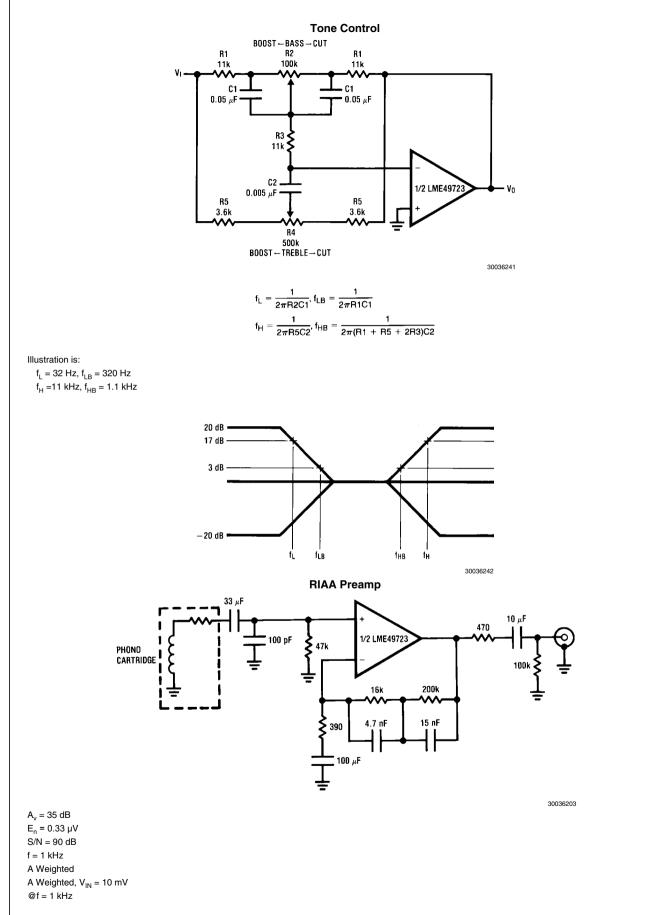


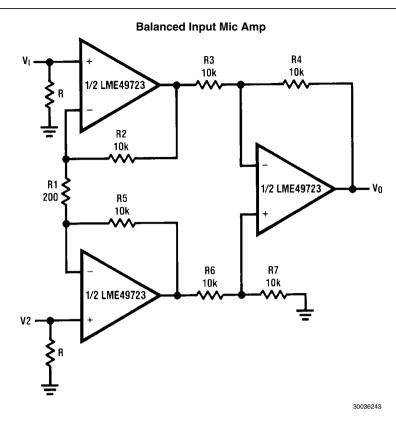






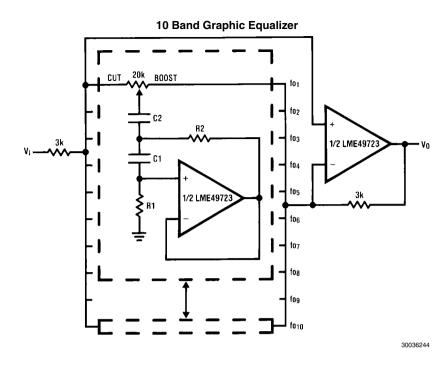






If R2 = R5, R3 = R6, R4 = R7 V0 = $\left(1 + \frac{2R2}{R1}\right)\frac{R4}{R3}(V2 - V1)$

Illustration is: V0 = 101(V2 - V1)



fo (Hz)	C ₁	C ₂	R ₁	R ₂
32	0.12µF	4.7µF	75kΩ	500Ω
64	0.056µF	3.3µF	68kΩ	510Ω
125	0.033µF	1.5µF	62kΩ	510Ω
250	0.015µF	0.82µF	68kΩ	470Ω
500	8200pF	0.39µF	62kΩ	470Ω
1k	3900pF	0.22µF	68kΩ	470Ω
2k	2000pF	0.1µF	68kΩ	470Ω
4k	1100pF	0.056µF	62kΩ	470Ω
8k	510pF	0.022µF	68kΩ	510Ω
16k	330pF	0.012µF	51kΩ	510Ω

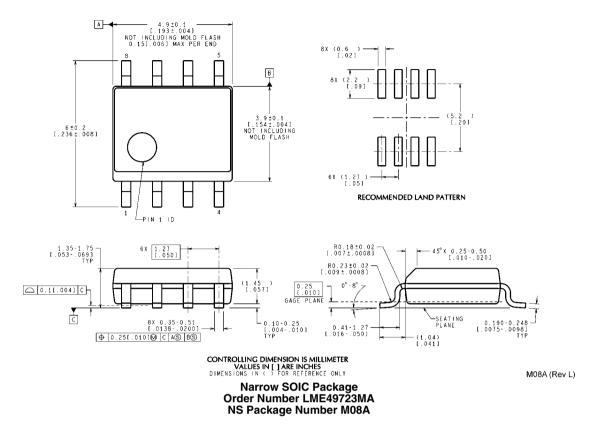
Note 9: At volume of change = $\pm 12 \text{ dB}$

Q = 1.7

Reference: "AUDIO/RADIO HANDBOOK", National Semiconductor, 1980, Page 2-61

Revision History					
	Rev	Date	Description		
	1.0	01/07/08	Initial release.		
	1.01	02/11/08	Text edits.		

Physical Dimensions inches (millimeters) unless otherwise noted



Notes

Notes

Pr	oducts	Design Support		
Amplifiers	www.national.com/amplifiers	WEBENCH Analog University	www.national.com/webench www.national.com/AU www.national.com/appnotes www.national.com/contacts	
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